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AN1403 Application Note

FACT™ I/O Model Kit

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This application note provides the SPICE information necessary to allow the customer to perform system level interconnect modelling for the Motorola FACT logic family. It is not intended for the purpose of performing extensive device modelling.

FACT is a trademark of National Semiconductor Corp.





FACT I/O Model Kit

Objective

The objective of providing a spice modelling kit is to allow the customer to perform system level interconnect modelling for the Motorola FACT logic family. It is not intended for the purpose of performing extensive device modelling.

Schematic Information

The kit contains representative circuit schematics of the different I/O structures and a worst case package model schematic used in the FACT family.

Input Structures

There are three basic variations of the input structures (Figures 1, 2, and 3). In all of the schematics the clamping diodes are shown and the appropriate PMOS:NMOS ratios of the inverter stage. Actual MOS gate sizes may vary but the ratio will be maintained. The variation of size is the result of custom designing each functional device for speed, which my require different build up ratios (BUR). For 74ACxxx devices both Motorola and National (second source) uses the identical Input buffer structures. However, the for 74ACTxxx devices (TTL input buffer) will vary depending on the source of the design. Once again, the appropriate P:N ratios are depicted in the figures.

Output Structure

There are two represented output structures (Figures 4, 5) one is the standard output buffer and the other is with tri-state. The size range of this standard output buffer is listed in the figure as:

P-channel (1570 – 1900) N-channel (780 – 900)

Typically Motorola designs use a 1600/800 size output buffer.

Transistor Parameters for Typical FACT Output Buffers

1600/800 FACT Output Buffer

PMOS L=2U W=1599U AD=5192.8P AS=4504.1P PD=1690.4U PS=1874.7U+NRD=9.375E-4 NRS=9.375E-4

NMOS L=2U W=799U AD=2596.4P AS=2502.3P PD=845.2U PS=1041.5U +NRD=1.875E-3 NRS=1.875E-3

1900/900 FACT Output Buffer

PMOS L=2U W=1899U AD=6163.6P AS=5227.3P PD=2013.0U PS=2181.3U +NRD=7.895E-4 NRS=7.895E-4

NMOS L=2U W=899U AD=2918.0P AS=2699.7P PD=956.5U PS=1129.8U +NRD=1.667E-3 NRS=1.667E-3

Package Model

The package model represents the parasitics as they are seen on a corner pin GND & V_{CC} for a 20-pin plastic DIP type package (Figure 6). For 14-pin and 16-pin plastic DIP packages reduce inductance by 20% from the 20 pin model. To simulate SOIC type package reduce the inductance of the appropriate DIP model by 50%.

Spice Parameter Information

In addition to the schematics, a listing of the spice parameters for the transistors are referenced and included (Page 4). These parameters can be used for best, typical and worst case simulations.

Summary

The information included in this kit should provide the basic information necessary to do Spice level interconnect modelling. If any clarification or additional information is necessary the user is encouraged to contact the FACT Applications or Design personnel for assistance.

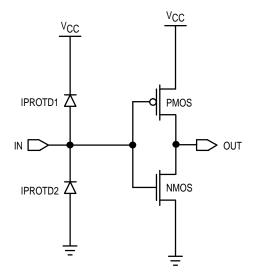
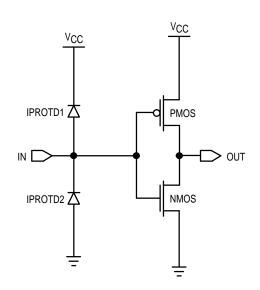


Figure 1. National/Motorola 74ACxxx Input Buffer P/N Ratio = 'P:N = 2.5:1'

AN1403



IPROTD1 A PMOS 2 BUF OUT IN PROTD2 A NMOS I BUF

VCC

1BUFD

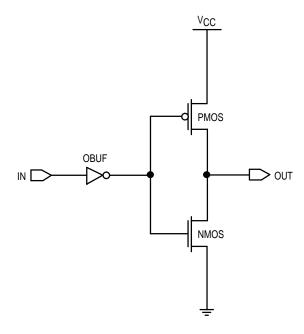
VCC

VCC

PMOS

Figure 2. National 74ACTxxx TTL Input Buffer P/N Ratio = 'P:N = 1:4'

Figure 3. Motorola 74ACTxxx TTL Input Buffer 1 BUF P/N Ratio = 'P:N = 1:2.5' 2 BUF P/N Ratio = 'P:N = 1:1'





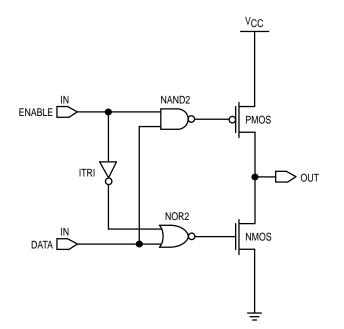


Figure 5. Standard Tri-State Output Buffer P-Channel Device Size Range (1570 \rightarrow 1900) N-Channel Device Size Range (780 \rightarrow 900)

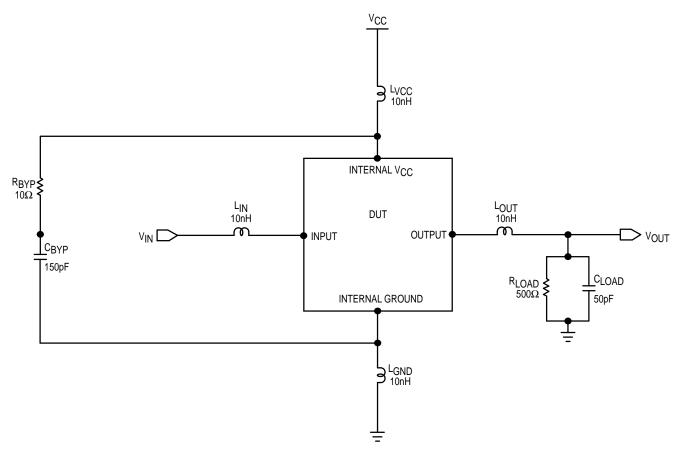


Figure 6. Package Model for FACT Circuits

MSPICE Simulation Cards

Note: \$BPBN – Best PMOS, Best NMOS \$BPWN – Best PMOS, Worst NMOS \$TPTN – Typical PMOS, Typical NMOS \$WPBN – Worst PMOS, Best NMOS \$WPWN – Worst PMOS, Worst NMOS	
\$BPBN .MODEL NMOS NMOS LEVEL= 3 + + + +	VTO=0.525 TOX=2.3E-8 NSUB=2.9E16 XJ=2.5E-7 LD=4.75E-7 UO=537.8 VMAX=1.45E5 DELTA =1.4 THETA=0.038 ETA=0.12 KAPPA=0.06 RSH=40 NFS=2.4E11 CGSO=3.5E-10 CGDO=3.5E-10 PB=0.95 CJ=5.8E-4 MJ=0.4 CJSW=1.1E-9 MJSW=0.36 TPG=1 XQC=0.4
.MODEL PMOS PMOS LEVEL=3 + + + + # \$BPWN	VTO=-0.55 TOX=2.3E-8 NSUB=1E16 XJ=3E-7 LD=4.75E-7 UO=199.7 VMAX=1.4E5 DELTA=0.75 THETA=0.08 ETA=0.09 KAPPA=2.5 RSH=120 NFS=1.68E11 CGSO=6.2E-10 CGDO=6.2E-10 PB=0.87 CJ=2.42E-4 MJ=0.4 CJSW=4.66E-10 MJSW=0.36 TPG=-1 XQC=0.4
# .MODEL PMOS PMOS LEVEL=3 + + + +	VTO=-0.55 TOX=2.3E-8 NSUB=1E16 XJ=3E-7 LD=4.75E-7 UO=199.7 VMAX=1.4E5 DELTA=0.75 THETA=0.08 ETA=0.09 KAPPA=2.5 RSH=120 NFS=1.68E11 CGSO=6.2E-10 CGDO=6.2E-10 PB=0.87 CJ=2.42E-4 MJ=0.4 CJSW=4.66E-10 MJSW=0.36 TPG=-1 XQC=0.4

AN1403

.MODEL NMOS NMOS LEVEL=3 + + + + # \$TPTN #	VTO=0.865 TOX=2.8E-8 NSUB=2.9E16 XJ=2.5E-7 LD=2.25E-7 UO=537.8 VMAX=1.45E5 DELTA=1.4 THETA=0.038 ETA=0.12 KAPPA=0.06 RSH=60 NFS=2.4E11 CGSO=3.5E-10 CGDO=3.5E-10 PB=0.95 CJ=5.8E-4 MJ=0.4 CJSW=1.1E-9 MJSW=0.36 TPG=1 XQC=0.4
	VTO=0.695 TOX=2.55E-8 NSUB=2.9E16 XJ=2.5E-7 LD=3.5E-7 UO=537.8 VMAX=1.45E5 DELTA=1.4 THETA=0.038 ETA=0.12 KAPPA=0.06 RSH=41 NFS=2.4E11 CGSO=3.5E-10 CGDO=3.5E-10 PB=0.95 CJ=5.8E-4 MJ=0.4 CJSW=1.1E-9 MJSW=0.36 TPG=1 XQC=0.4
.MODEL PMOS PMOS LEVEL=3 + + + + * * *	VTO=-0.72 TOX=2.55E-8 NSUB=1E16 XJ=3E-7 LD=3.5E-7 UO=199.7 VMAX=1.4E5 DELTA=0.75 THETA=0.08 ETA=0.09 KAPPA=2.5 RSH=146 NFS=1.68E11 CGSO=6.2E-10 CGDO=6.2E-10 PB=0.87 CJ=2.42E-4 MJ=0.4 CJSW=4.66E-10 MJSW=0.36 TPG=-1 XQC=0.4
# .MODEL NMOS NMOS LEVEL= 3 + + + +	VTO=0.525 TOX=2.3E-8 NSUB=2.9E16 XJ=2.5E-7 LD=4.75E-7 UO=537.8 VMAX=1.45E5 DELTA =1.4 THETA=0.038 ETA=0.12 KAPPA=0.06 RSH=40 NFS=2.4E11 CGSO=3.5E-10 CGDO=3.5E-10 PB=0.95 CJ=5.8E-4 MJ=0.4 CJSW=1.1E-9 MJSW=0.36 TPG=1 XQC=0.4
.MODEL PMOS PMOS LEVEL=3 + + + + + # \$WPWN	VTO=-0.89 TOX=2.8E-8 NSUB=1E16 XJ=3E-7 LD=2.25E-7 UO=199.7 VMAX=1.4E5 DELTA=0.75 THETA=0.08 ETA=0.09 KAPPA=2.5 RSH=160 NFS=1.68E11 CGSO=6.2E-10 CGDO=6.2E-10 PB=0.87 CJ=2.42E-4 MJ=0.4 CJSW=4.66E-10 MJSW=0.36 TPG=-1 XQC=0.4
# .MODEL NMOS NMOS LEVEL=3 + + + +	VTO=0.865 TOX=2.8E-8 NSUB=2.9E16 XJ=2.5E-7 LD=2.25E-7 UO=537.8 VMAX=1.45E5 DELTA=1.4 THETA=0.038 ETA=0.12 KAPPA=0.06 RSH=60 NFS=2.4E11 CGSO=3.5E-10 CGDO=3.5E-10 PB=0.95 CJ=5.8E-4 MJ=0.4 CJSW=1.1E-9 MJSW=0.36 TPG=1 XQC=0.4
.MODEL PMOS PMOS LEVEL=3 + + + +	VTO=-0.89 TOX=2.8E-8 NSUB=1E16 XJ=3E-7 LD=2.25E-7 UO=199.7 VMAX=1.4E5 DELTA=0.75 THETA=0.08 ETA=0.09 KAPPA=2.5 RSH=160 NFS=1.68E11 CGSO=6.2E-10 CGDO=6.2E-10 PB=0.87 CJ=2.42E-4 MJ=0.4 CJSW=4.66E-10 MJSW=0.36 TPG=-1 XQC=0.4

AN1403

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